

#### NCE N-Channel Enhancement Mode Power MOSFET

#### **Description**

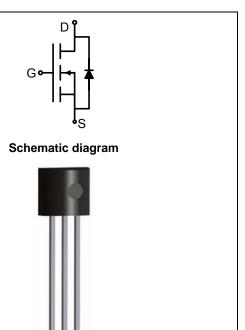
The NCE0202ZA uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

- $V_{DS}$  = 200V, $I_D$  =2A  $R_{DS(ON)}$  < 580mΩ @  $V_{GS}$ =10V (Typ:520mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

## **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



TO-92 view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
N0202	NCE0202ZA	TO-92	-	-	-

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	200	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	2	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	8	Α
Maximum Power Dissipation	P <sub>D</sub>	3	W
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}\!$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	41.7	°C/W
	00/1		i e

## **Electrical Characteristics (T<sub>A</sub>=25**°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	200	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V	-	-	1	μA



# http://www.ncepower.com

# NCE0202ZA

Gate-Body Leakage Current	I <sub>GSS</sub>	I <sub>GSS</sub> V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V		-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	1.2	1.8	2.5	V	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =2A	-	520	580	mΩ	
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =15V,I <sub>D</sub> =2A		8	-	S	
Dynamic Characteristics (Note4)							
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V,	-	580	-	PF	
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> -23V,V <sub>GS</sub> -0V, F=1.0MHz	-	90	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0WHZ	-	3	-	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t <sub>d(on)</sub>		-	10	-	nS	
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =100V, $R_L$ =15 $\Omega$	-	12	-	nS	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GS}$ =10 $V$ , $R_{G}$ =2.5 $\Omega$	-	15	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS	
Total Gate Charge	$Q_g$	\/ -100\/   -24	-	12		nC	
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ =100V, $I_{D}$ =2A, $V_{GS}$ =10V	-	2.5	-	nC	
Gate-Drain Charge	Q <sub>gd</sub>	VGS-10V	-	3.8	-	nC	
Drain-Source Diode Characteristics	·						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =2A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is			-	2	Α	

#### Notes:

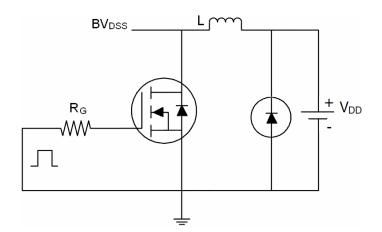
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production

**Pb Free Product** 

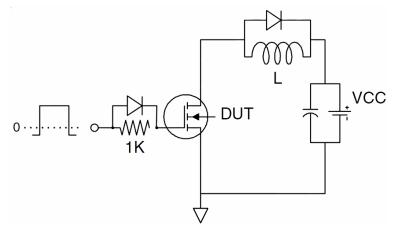


# **Test Circuit**

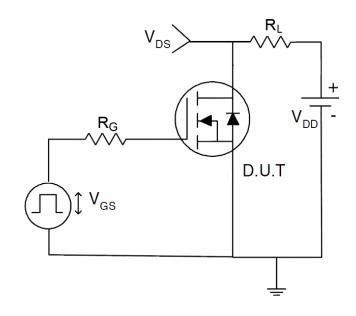
## 1) E<sub>AS</sub> test circuit



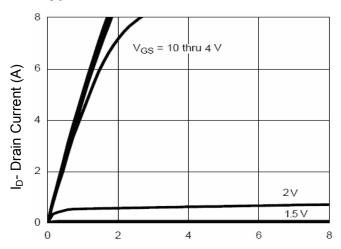
## 2) Gate charge test circuit



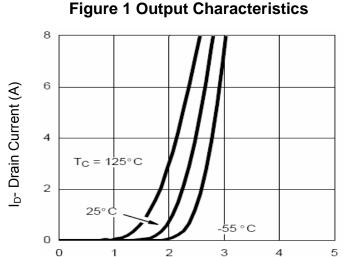
#### 3) Switch Time Test Circuit



# **Typical Electrical and Thermal Characteristics (Curves)**



Vds Drain-Source Voltage (V)



Vgs Gate-Source Voltage (V)
Figure 2 Transfer Characteristics

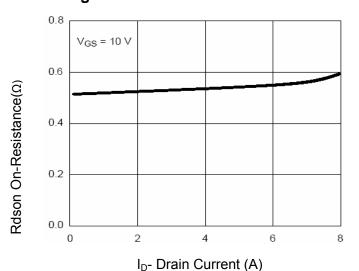
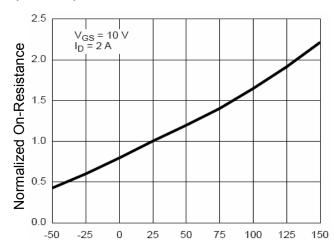


Figure 3 Rdson- Drain Current



 $T_J$ -Junction Temperature (°C) **Figure 4 Rdson-JunctionTemperature** 

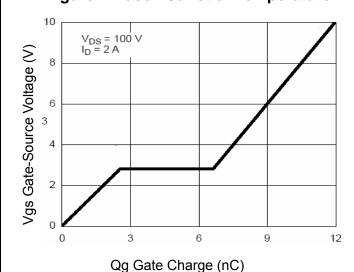


Figure 5 Gate Charge

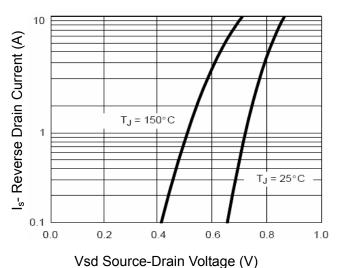
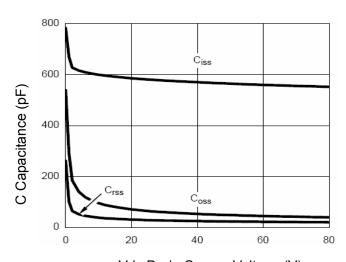
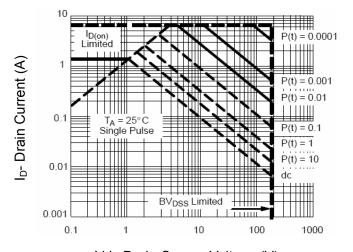


Figure 6 Source- Drain Diode Forward



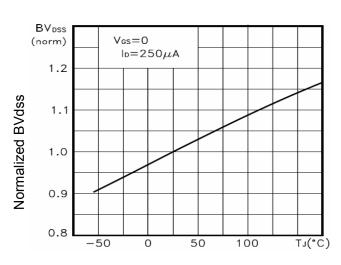
Vds Drain-Source Voltage (V)

Figure 7 Capacitance vs Vds



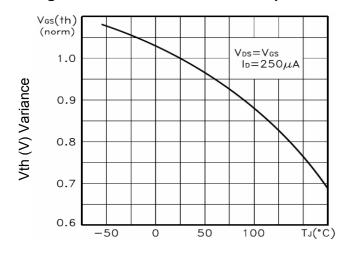
Vds Drain-Source Voltage (V)

**Figure 8 Safe Operation Area** 



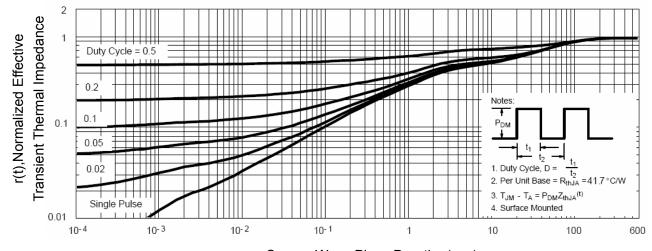
T<sub>J</sub>-Junction Temperature(°C)

Figure 9 BV<sub>DSS</sub> vs Junction Temperature



T<sub>J</sub>-Junction Temperature(°C)

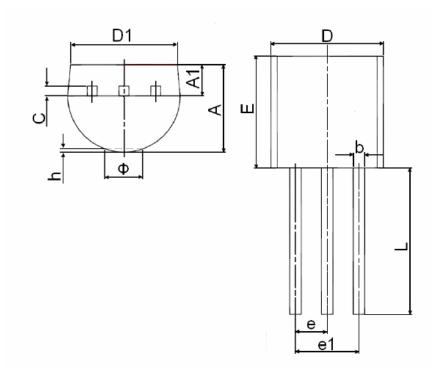
Figure 10 V<sub>GS(th)</sub> vs Junction Temperature



Square Wave Pluse Duration(sec)

**Figure 11 Normalized Maximum Transient Thermal Impedance** 

# **TO-92 Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
Α	3.300	3.700	0.130	0.146		
A1	1.100	1.400	0.043	0.055		
b	0.380	0.550	0.015	0.022		
С	0.360	0.510	0.014	0.020		
D	4.400	4.700	0.173	0.185		
D1	3.430		0.135			
Е	4.300	4.700	0.169	0.185		
е	1.270	TYP	0.050 TYP			
e1	2.440	2.640	0.096	0.104		
L	14.100	14.500	0.555	0.571		
Ф		1.600		0.063		
h	0.000	0.380	0.000	0.015		

#### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$

**Pb-Free Product** 

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